

PATENT APPLICATION  
Docket No. 9898-339

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Yoon-Jong Song, et al.

Serial No.: not yet assigned                      Art Unit: not yet assigned  
Filed: November 24, 2003                      Examiner: not yet assigned  
For: FERROELECTRIC MEMORY DEVICE USING VIA ETCH-STOP  
LAYER AND METHOD FOR MANUFACTURING THE SAME

Mail Stop Patent Publication  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Applicant submits herewith PTO Form 1449 listing patents and publications of which he is aware which may be material to the examination of this application and in respect of which there may be a duty to disclose in accordance with 37 CFR Section 1.56.

The above-referenced application is a divisional of U.S. Serial No. 10/354,651, filed January 29, 2003, now pending.

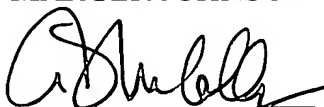
It includes the same disclosure as U.S. patent application Serial No. 10/354,651.

It is understood that the listed references will be considered in the examination of the application and that no separate copies of the same prior art are required to be provided since they were previously cited or transmitted in the foregoing prior application. 37 CFR Section 1.98(d). Form(s) PTO 1449 is enclosed listing references cited by the Examining Attorney and submitted by applicant in the prior applications.

Customer No. 20575

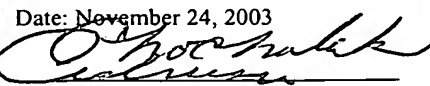
Respectfully submitted,

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I hereby certify that this correspondence is being deposited with the United States Postal Service as Express mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450  
Date: November 24, 2003  
  
Adrienne Chocholak

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**INFORMATION DISCLOSURE CITATION**  
**FORM PTO-1449 (Modified)**

**U.S. PATENT DOCUMENTS**

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Issue</u> <u>Date</u>	<u>Name</u>	<u>Class</u>	<u>Sub</u> <u>Class</u>
_____	_____	6,600,185	7/2003	Tani, et al.		

Examiner: \_\_\_\_\_

Date Considered: \_\_\_\_\_